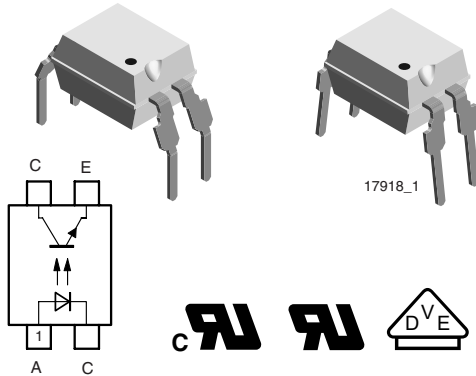


## Optocoupler, Phototransistor Output, High Temperature, 110 °C Rated



### DESCRIPTION

The TCET1110/ TCET1110G consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4-pin plastic dual inline package.

The elements are mounted on one leadframe, providing a fixed distance between input and output for highest safety requirements.

### VDE STANDARDS

These couplers perform safety functions according to the following equipment standards:

- **DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending**  
Optocoupler for electrical safety requirements
- **IEC 60950**  
Office machines (applied for reinforced isolation for mains voltage  $\leq 400 V_{RMS}$ )
- **VDE 0804**  
Telecommunication apparatus and data processing
- **IEC 60065**  
Safety for mains-operated electronic and related household apparatus

### APPLICATIONS

- Switch-mode power supplies
- Line receiver
- Computer peripheral interface
- Microprocessor system interface
- Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):
  - for appl. class I - IV at mains voltage  $\leq 300 V$
  - for appl. class I - III at mains voltage  $\leq 600 V$
 according to DIN EN 60747-5-2 (VDE 0884)/ DIN EN 60747-5-5 pending.

### FEATURES

- CTR offered in 9 groups
- Isolation materials according to UL94-VO
- Pollution degree 2 (DIN/VDE 0110/resp. IEC 60664)
- Climatic classification 55/100/21 (IEC 60068 part 1)
- Special construction: therefore, extra low coupling capacity of typical 0.2 pF, high **Common Mode Rejection**
- Low temperature coefficient of CTR
- Temperature range - 40 to + 110 °C
- Rated impulse voltage (transient overvoltage)  $V_{IOTM} = 8 kV_{peak}$
- Isolation test voltage (partial discharge test voltage)  $V_{pd} = 1.6 kV$
- Rated isolation voltage (RMS includes DC)  $V_{IOWM} = 600 V_{RMS}$
- Rated recurring peak voltage (repetitive)  $V_{IORM} = 848 peak$
- Creepage current resistance according to VDE 0303/ IEC 60112 **Comparative Tracking Index: CTI  $\geq 175$**
- Thickness through insulation  $\geq 0.75 mm$
- External creepage distance  $> 8 mm$
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### AGENCY APPROVALS

- UL1577, file no. E76222 system code U, double protection
- BSI: EN 60065:2002, EN 60950:2000 certificate no. 7081 and 7402
- DIN EN 60747-5-2 (VDE 0884)  
DIN EN 60747-5-5 pending
- FIMKO

# TCET1110/TCET1110G



Vishay Semiconductors Optocoupler, Phototransistor Output,  
High Temperature, 110 °C Rated

ORDER INFORMATION	
PART	REMARKS
TCET1110	CTR 50 to 600 %, DIP-4
TCET1111	CTR 40 to 80 %, DIP-4
TCET1112	CTR 63 to 125 %, DIP-4
TCET1113	CTR 100 to 200 %, DIP-4
TCET1114	CTR 160 to 320 %, DIP-4
TCET1115	CTR 50 to 150 %, DIP-4
TCET1116	CTR 100 to 300 %, DIP-4
TCET1117	CTR 80 to 160 %, DIP-4
TCET1118	CTR 130 to 260 %, DIP-4
TCET1119	CTR 200 to 400 %, DIP-4
TCET1110G	CTR 50 to 600 %, DIP-4
TCET1111G	CTR 40 to 80 %, DIP-4
TCET1112G	CTR 63 to 125 %, DIP-4
TCET1113G	CTR 100 to 200 %, DIP-4
TCET1114G	CTR 160 to 320 %, DIP-4
TCET1115G	CTR 50 to 150 %, DIP-4
TCET1116G	CTR 100 to 300 %, DIP-4
TCET1117G	CTR 80 to 160 %, DIP-4
TCET1118G	CTR 130 to 260 %, DIP-4
TCET1119G	CTR 200 to 400 %, DIP-4

## Note

4 Pin = single channel

G = lead form 10.16 mm; G is not marked on the body

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>INPUT</b>				
Reverse voltage		$V_R$	6	V
Forward current		$I_F$	60	mA
Forward surge current	$t_p \leq 10 \mu s$	$I_{FSM}$	1.5	A
<b>OUTPUT</b>				
Collector emitter voltage		$V_{CEO}$	70	V
Emitter collector voltage		$V_{ECO}$	7	V
Collector current		$I_C$	50	mA
Collector peak current	$t_p/T = 0.5, t_p \leq 10 ms$	$I_{CM}$	100	mA
<b>COUPLER</b>				
Isolation test voltage (RMS)	$t = 1 min$	$V_{ISO}$	5000	$V_{RMS}$
Operating ambient temperature range		$T_{amb}$	- 40 to + 110	°C
Storage temperature range		$T_{stg}$	- 55 to + 125	°C
Soldering temperature	2 mm from case, $\leq 10 s$	$T_{sld}$	260	°C

## Note

$T_{amb} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified.

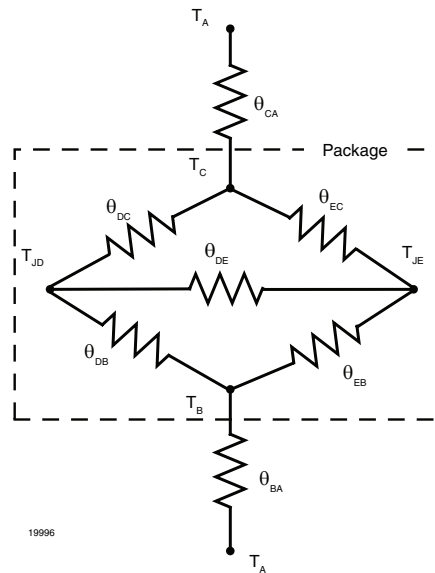
Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.



THERMAL CHARACTERISTICS (1)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
LED power dissipation	at 25 °C	$P_{diss}$	100	mW
Output power dissipation	at 25 °C	$P_{diss}$	150	mW
Maximum LED junction temperature		$T_{jmax}$	125	°C
Maximum output die junction temperature		$T_{jmax}$	125	°C
Thermal resistance, junction emitter to board		$\theta_{EB}$	173	°C/W
Thermal resistance, junction emitter to case		$\theta_{EC}$	149	°C/W
Thermal resistance, junction detector to board		$\theta_{DB}$	111	°C/W
Thermal resistance, junction detector to case		$\theta_{DC}$	127	°C/W
Thermal resistance, junction emitter to junction detector		$\theta_{ED}$	173	°C/W
Thermal resistance, board to ambient(2)		$\theta_{BA}$	197	°C/W
Thermal resistance, case to ambient(2)		$\theta_{CA}$	4041	°C/W

### Notes

- (1) The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's Thermal Characteristics of optocouplers application note.
- (2) For 2 layer FR4 board (4" x 3" x 0.062)



ELECTRICAL CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>						
Forward voltage	$I_F = 50 \text{ mA}$	$V_F$		1.25	1.6	V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	$C_j$		50		pF
<b>OUTPUT</b>						
Collector emitter voltage	$I_C = 1 \text{ mA}$	$V_{CEO}$	70			V
Emitter collector voltage	$I_E = 100 \mu\text{A}$	$V_{ECO}$	7			V
Collector emitter cut-off current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	$I_{CEO}$		10	100	nA
<b>COUPLER</b>						
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	$V_{CEsat}$			0.3	V
Cut-off frequency	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 100 \Omega$	$f_c$		110		kHz
Coupling capacitance	$f = 1 \text{ MHz}$	$C_k$		0.3		pF

**Note**

$T_{amb} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
$I_C/I_F$	$V_{CE} = 5 \text{ V}, I_F = 1 \text{ mA}$	TCET1111 TCET1111G	CTR	13	30		%
		TCET1112 TCET1112G	CTR	22	45		%
		TCET1113 TCET1113G	CTR	34	70		%
		TCET1114 TCET1114G	CTR	56	90		%
	$V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$	TCET1110 TCET1110G	CTR	50		600	%
		TCET1115 TCET1115G	CTR	50		150	%
		TCET1116 TCET1116G	CTR	100		300	%
		TCET1117 TCET1117G	CTR	80		160	%
		TCET1118 TCET1118G	CTR	130		260	%
		TCET1119 TCET1119G	CTR	200		400	%
	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$	TCET1111 TCET1111G	CTR	40		80	%
		TCET1112 TCET1112G	CTR	63		125	%
		TCET1113 TCET1113G	CTR	100		200	%
		TCET1114 TCET1114G	CTR	160		320	%



MAXIMUM SAFETY RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>						
Forward current		$I_F$			130	mA
<b>OUTPUT</b>						
Power dissipation		$P_{diss}$			265	mW
<b>COUPLER</b>						
Rated impulse voltage		$V_{IOTM}$			8	kV
Safety temperature		$T_{si}$			150	°C

**Note**

According to DIN EN 60747-5-2 (VDE0884)/ DIN EN 60747-5-5 pending (see figure 1). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

INSULATION RATED PARAMETERS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	100 %, $t_{test} = 1$ s	$V_{pd}$	1.6			kV
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60$ s, $t_{test} = 10$ s, (see figure 2)	$V_{IOTM}$	8			kV
		$V_{pd}$	1.3			kV
Insulation resistance	$V_{IO} = 500$ V	$R_{IO}$	$10^{12}$			$\Omega$
	$V_{IO} = 500$ V, $T_{amb} = 100$ °C	$R_{IO}$	$10^{11}$			$\Omega$
	$V_{IO} = 500$ V, $T_{amb} = 150$ °C (construction test only)	$R_{IO}$	$10^9$			$\Omega$

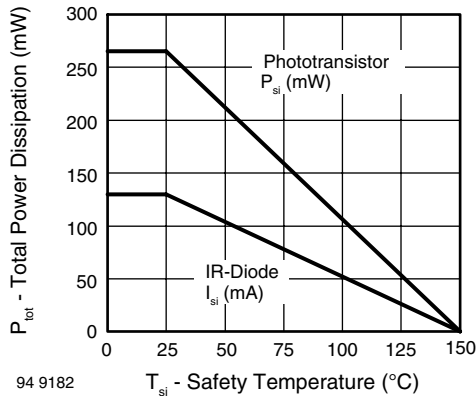


Fig. 1 - Derating Diagram

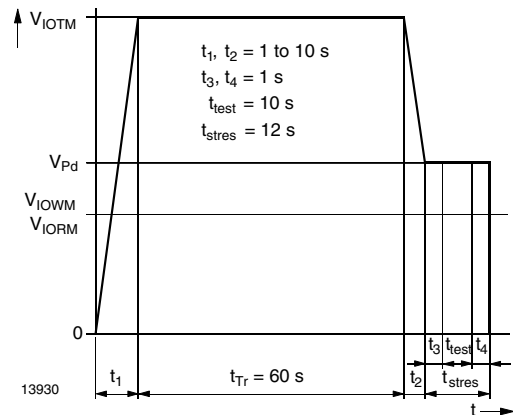


Fig. 2 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-; IEC60747

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT
Delay time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 3)	$t_d$		3		$\mu\text{s}$
Rise time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 3)	$t_r$		3		$\mu\text{s}$
Fall time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 3)	$t_f$		4.7		$\mu\text{s}$
Storage time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 3)	$t_s$		0.3		$\mu\text{s}$
Turn-on time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 3)	$t_{on}$		6		$\mu\text{s}$
Turn-off time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 3)	$t_{off}$		5		$\mu\text{s}$
Turn-on time	$V_S = 5\text{ V}$ , $I_F = 10\text{ mA}$ , $R_L = 1\text{ k}\Omega$ , (see figure 4)	$t_{on}$		9		$\mu\text{s}$
Turn-off time	$V_S = 5\text{ V}$ , $I_F = 10\text{ mA}$ , $R_L = 1\text{ k}\Omega$ , (see figure 4)	$t_{off}$		10		$\mu\text{s}$

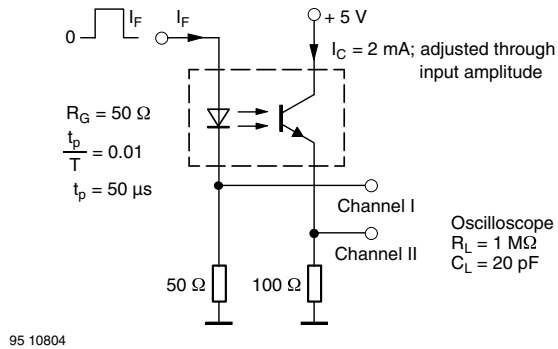


Fig. 3 - Test Circuit, Non-Saturated Operation

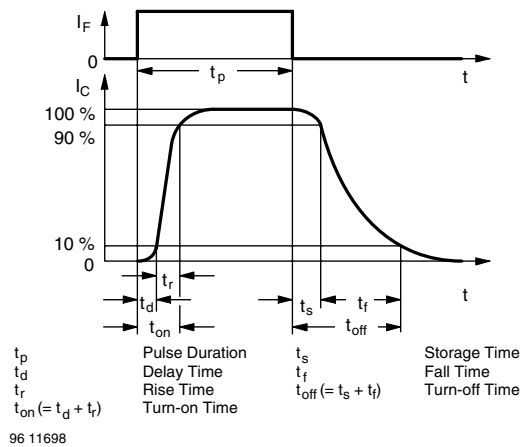


Fig. 5 - Switching Times

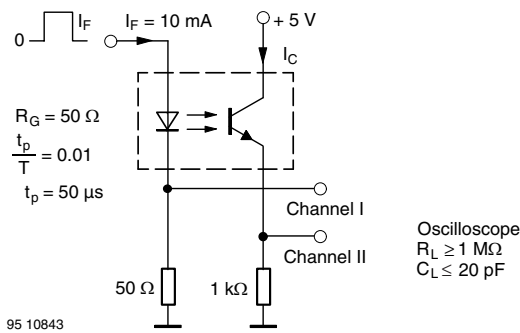


Fig. 4 - Test Circuit, Saturated Operation



**TYPICAL CHARACTERISTICS**

$T_{amb} = 25\text{ °C}$ , unless otherwise specified

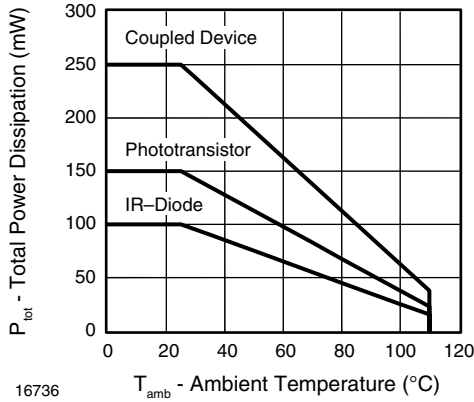


Fig. 6 - Total Power Dissipation vs. Ambient Temperature

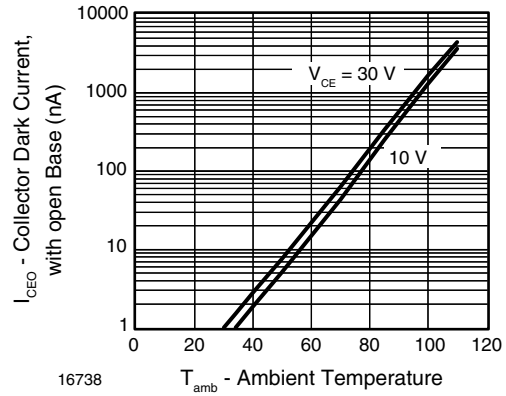


Fig. 9 - Collector Dark Current vs. Ambient Temperature

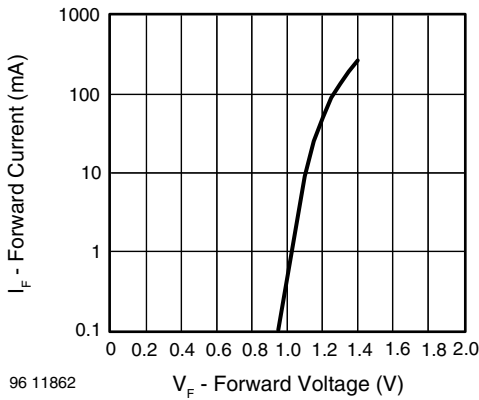


Fig. 7 - Forward Current vs. Forward Voltage

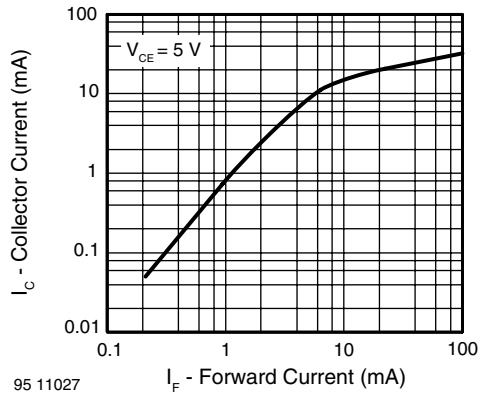


Fig. 10 - Collector Current vs. Forward Current

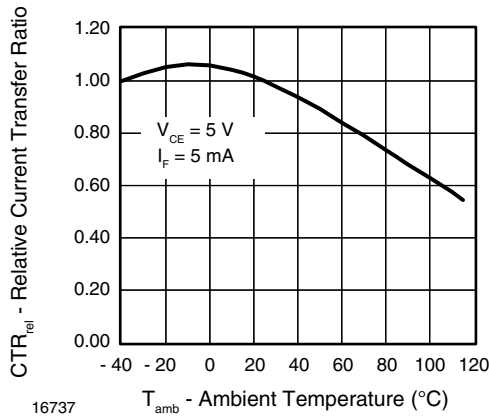


Fig. 8 - Relative Current Transfer Ratio vs. Ambient Temperature

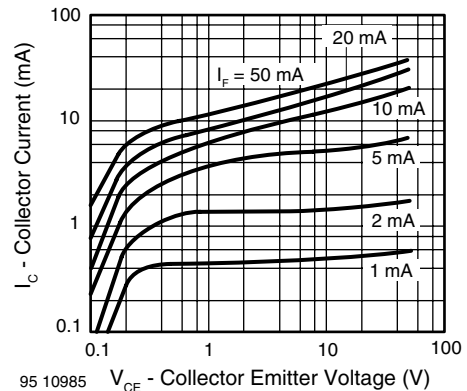


Fig. 11 - Collector Current vs. Collector Emitter Voltage

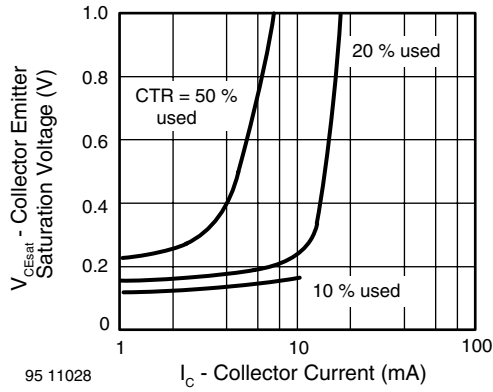


Fig. 12 - Collector Emitter Saturation Voltage vs. Collector Current

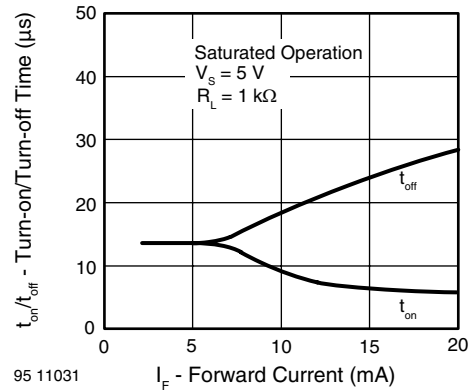


Fig. 15 - Turn-on/off Time vs. Forward Current

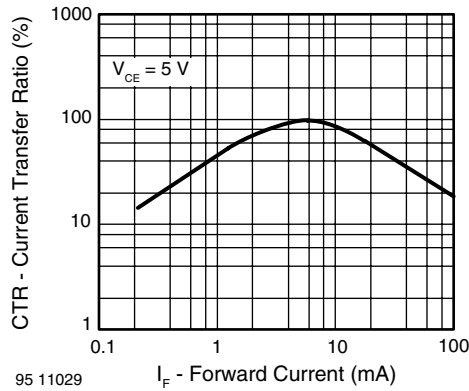


Fig. 13 - Current Transfer Ratio vs. Forward Current

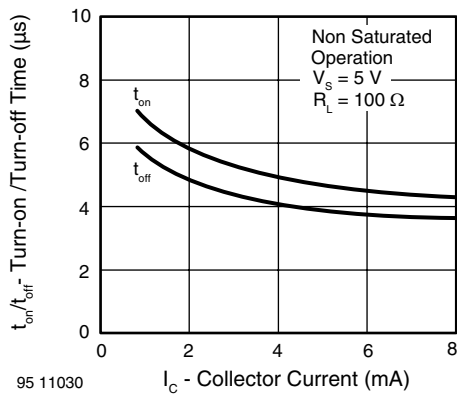


Fig. 14 - Turn-on/off Time vs. Collector Current

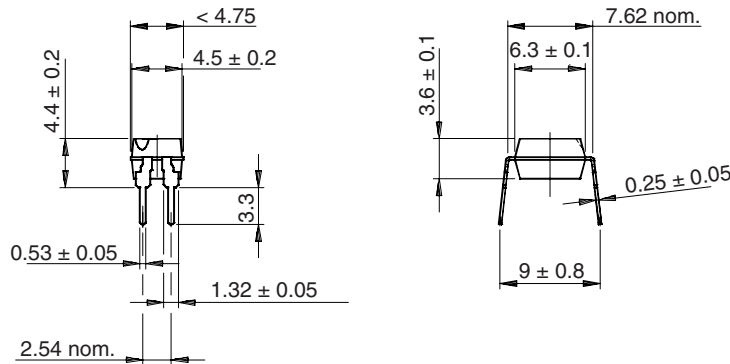




# TCET1110/TCET1110G

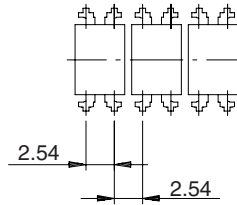
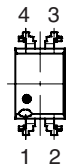
Optocoupler, Phototransistor Output, Vishay Semiconductors  
High Temperature, 110 °C Rated

## PACKAGE DIMENSIONS in millimeters

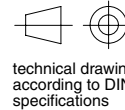


E. g.:  
Special Features: Endstackable  
to 2.54 mm (0.100") Spacing

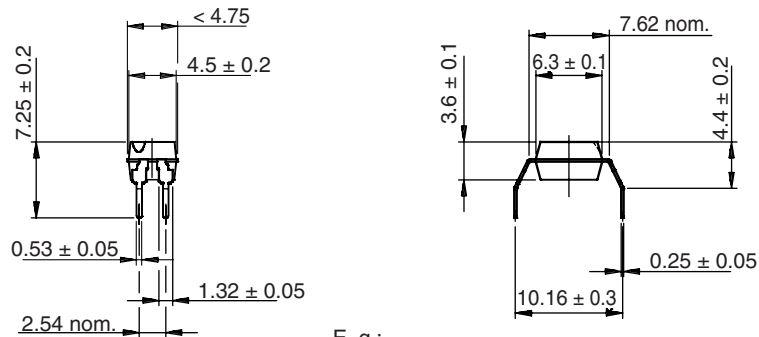
Weight: ca. 0.25 g  
Creepage Distance: > 6 mm  
Air Path: > 6 mm  
after Mounting on PC Board



Drawing-No.: 6.544-5302.03-4  
Issue: 5; 20.03.02

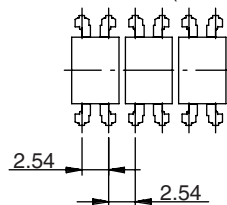
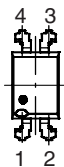


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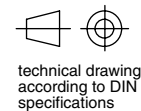


E. g.:  
Special Features: Endstackable  
to 2.54 mm (0.100") Spacing

Weight: ca. 0.25 g  
Creepage Distance: > 8 mm  
Air Path: > 8 mm  
after Mounting on PC Board



Drawing-No.: 6.544-5303.03-4  
Issue: 4; 20.03.02



14792

## **OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

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